

## Chapter 10: Op-amp circuits for detectors, filtering, and power applications.

We can improve the performance of most of the circuits we have built in this course, including RC circuits and rectifiers, by using op amps and negative feedback.

### I. Active Filters

#### A. RC Integrator and Low Pass Filters

Recall that a low pass circuit was an integrator for high frequencies. The RC integrator we built in the laboratory was limited as an integrator because the current charging the capacitor changed as the capacitor charged up. This meant that the circuit integrated only for small voltages.

By putting an integrating capacitor into the op-amp feedback loop, you force the input side of the capacitor to always be at the same voltage (virtual ground) so the input current no longer depends on how much charging it has done. This integrator works all the way up to the maximum output of the op amp. For the circuit shown, the output will be:

$$V_{OUT} = -\int V_{IN} \frac{dt}{RC}.$$

Of course, you must limit the low frequency behavior, or else the integrator will always be at the rail as it integrates any small offset voltage. This is done by putting in an extra resistor that will slowly bleed the charge of the capacitor over the time.

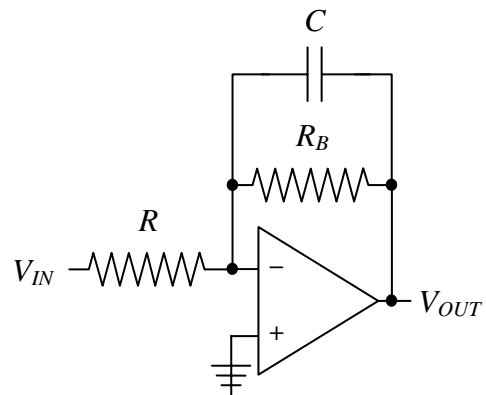


Figure 1: Op amp integrator (with low frequency limit).

#### B. RC Differentiator and High Pass Filters

Putting the capacitor at the input, and using a feedback resistor, you can construct an accurate differentiator. This time, your op amp will be stable with no input (if it has been internally compensated). For our circuit, the output is:

$$V_{OUT} = -RC \frac{dV_{IN}}{dt}$$

Note, though, that it has limited gain at high frequencies that will degrade its performance for fast derivatives.

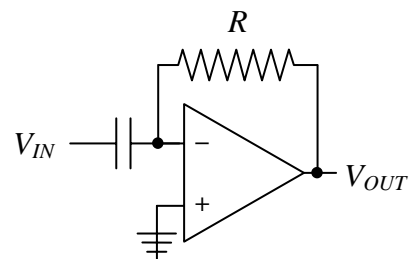


Figure 2: Op amp differentiator.

## II. Current Sources

The inherent negative feedback present in op-amp circuits is ideal for making high-impedance constant current sources. (why do ideal current sources have a high output impedance?)

### A. Op-Amp Current Source

A *current source* can be made from an inverting amplifier as shown in figure 3. The current in the load resistor must be the same as that in  $R_1$ . The current is then just the input voltage divided by  $R_1$ .

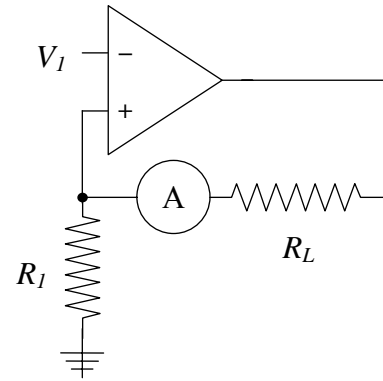


Figure 3: Current source.

### B. Op-Amp and Transistor Current Source

An op-amp can be combined with a transistor to make a current source in which the load is outside the feedback loop, as depicted in figure 4 below. The N-JFET transistor can be replaced by an NPN or a N-MOSFET transistor. The FET based circuits will have slightly better current regulation, and a MOSFET should be used for high current applications.

### C. Op-Amp and Transistor Current Source for Grounded Loads

The two previous circuits are excellent current sources, but they require that load be at some voltage above ground. Frequently, one side of the load must be grounded and in this case another similar circuit is required. Figure 5 shows the circuit diagram for a constant current source with grounded load based on P-JFET. The P-JFET can be replaced by a PNP or P-MOSFET for high current applications.

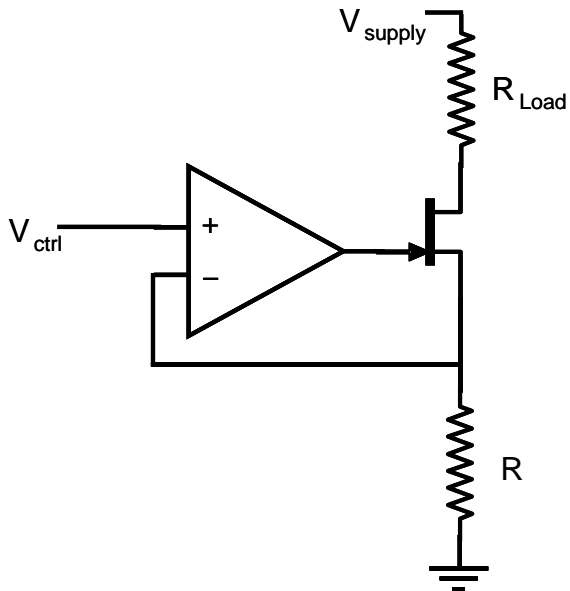


Figure 4: N-JFET constant current source - 2 -

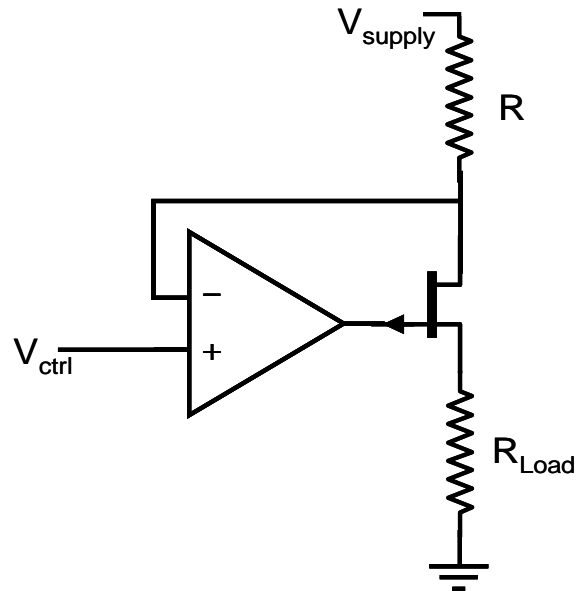


Figure 5: P-JFET constant current source

### III. Op-amp Power Amplifiers

Op-amps are quasi-perfect amplifiers, but they cannot source and sink a lot of current, which is necessary in high power application. The combination of an op-amp with one or more transistors can produce a high-quality amplifier. The high-impedance input of the op-amp provides high fidelity signal measurement and gain, while the output transistors provide high-current. The inclusion of the output transistors in the op-amp feedback loop helps linearize amplifier performance.

#### A. Op-amp with Emitter-Follower

An op-amp and an NPN emitter-follower (see chapter 6) can be combined to make a class A power amplifier as depicted in figure 6 below. Since the NPN transistor can only source current (i.e. the current can only go from *collector* to *emitter*), the input of the op-amp,  $V_{in}$ , must still have a positive bias.

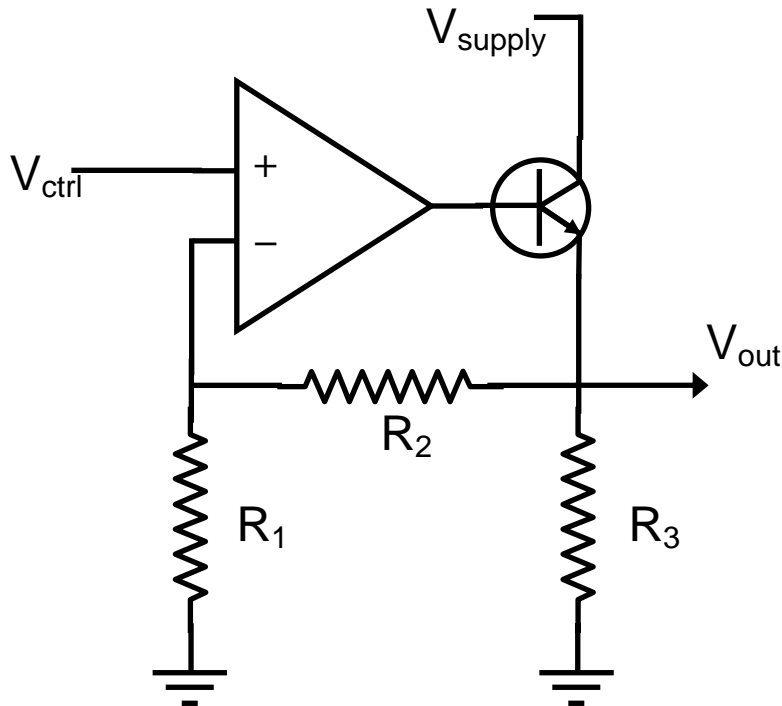


Figure 6: Non-inverting amplifier with emitter-follower in feedback loop.

#### B. Op-amp with Push-Pull Buffer

The push-pull amplifier we saw in chapter 7 can also be incorporated in the feedback loop of an op-amp inverting amplifier to make the class B bipolar power amplifier shown in figure 7 below. The feedback loop automatically removes the cross-over distortion due to the 0.6 V diode drops so long as the slew rate of the op-amp can keep up.

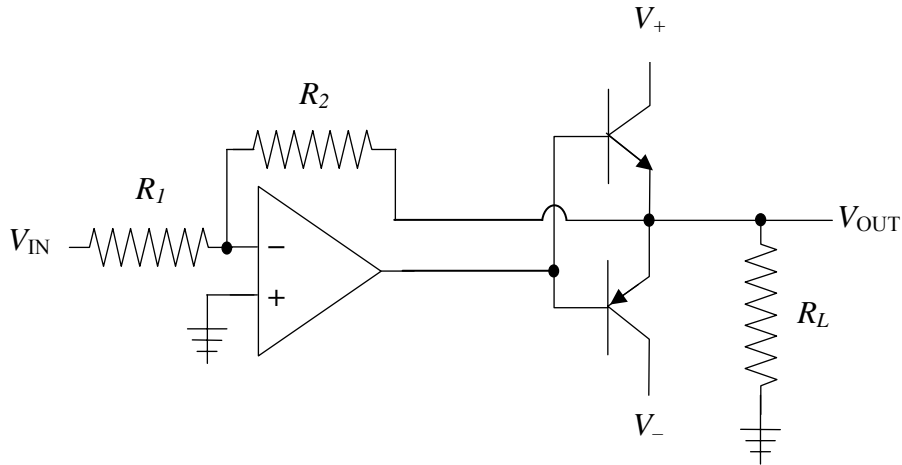


Figure 7: Inverting amplifier with a push-pull buffer inside the feedback loop.

## IV. Op-amp Rectifiers

If you put a diode in the feedback loop of an op-amp (along with a resistor to let the inverting input float), you can build a rectifier that eliminates the problems for voltages less than 0.6 V as the diode turns on (see figure 8).

The improved rectifier circuit (see figure 9) keeps the output of the op-amp from being driven to the rails when the circuit is blocking the wrong sign input. Since your op-amp has a limited slew rate, this improves performance. It also eliminates the 0.6 V offset that a single diode introduces.

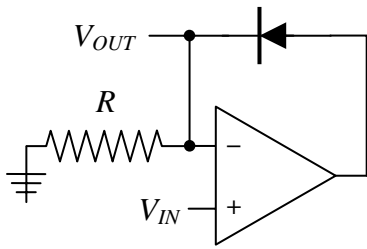


Figure 8: Op amp rectifier.

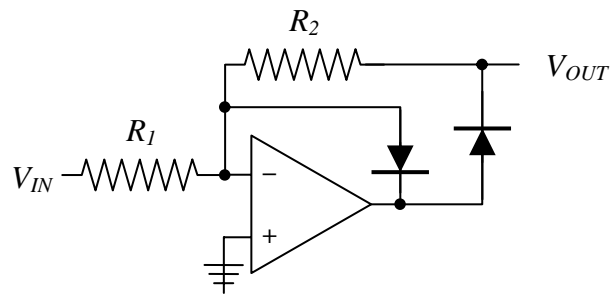


Figure 9: Improved op amp rectifier.

## IV. Photodiodes

Photodiodes are a type of diode which produce a reverse bias current when their PN junction is illuminated. The photo-current is proportional to the number of incident photons with quantum efficiencies of 0.5-0.9 photo-electrons per incident photon.

### A. High sensitivity photo-diode circuits

The simplest way to read the current on a photodiode is to convert it to a voltage with a resistor as shown in figure 10. This circuit is very simple, but has the disadvantage that the resistor loads the photodiode which must produce a voltage across the resistor. The photodiode also has a capacitance proportional to its area which will also determine time response ( $\tau = RC$ ): as this simple circuit makes clear, you cannot have high sensitivity and high speed at the same time.

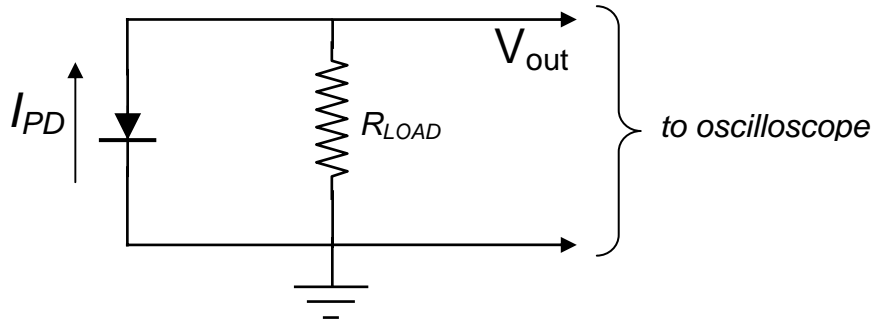


Figure 10: Photodiode with a resistive current-to-voltage converter.

As the voltage which the photodiode must produce becomes larger, the output current of the photodiode no longer remains proportional to the light intensity. An op-amp remedies this problem by keeping the voltage across the photodiode equal to zero for all light intensities, while also amplifying the signal in the current-to-voltage converter circuit of figure 11.

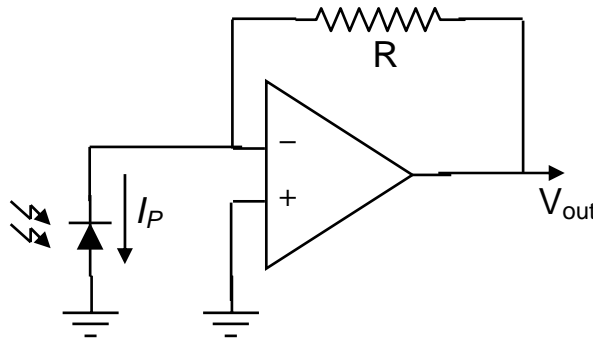


Figure 11: Photodiode with an op-amp current-to-voltage inverting amplifier.

### B. High speed photo-diode circuits

The PN junction capacitance of the photodiode can be reduced significantly by using a reverse-bias voltage on the photodiode, as shown in the circuit diagram on the right (figure 12). Since the capacitance drops, so does the time response (still  $\tau = RC$ ) of the photodiode. In practice, the fastest photodiode have very small detection areas and are operated in reverse-biased mode with small load resistors. While reverse biasing helps too improve the time response of the photodiode to fast signals, it also reduces its

sensitivity to very weak light signals, since the reverse bias voltage also drives a small leakage current across the PN junction. This larger leakage current, or dark current, has noise associated with it which limits the sensitivity of the photodiode at very low light levels.

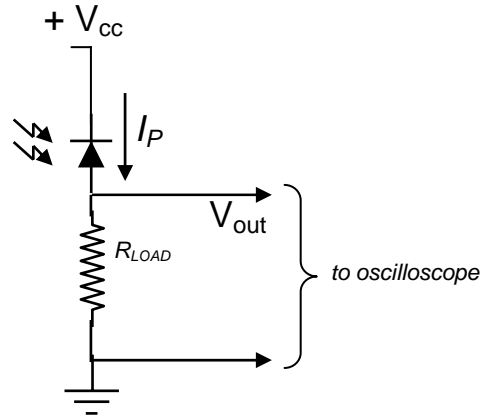


Figure 12: Photodiode in reverse-bias configuration with resistive load.

One problem with the simple reverse-bias circuit of figure 12 is that as the photocurrent increases at higher light intensities, the effective biasing voltage across the PN junction changes as well, which introduces a non-linear response into the behavior of the photo-detector. An op-amp can be used to keep the photodiode reverse-bias voltage constant for all illumination intensities, while also converting the photo-current to an amplified voltage (see figure 13).

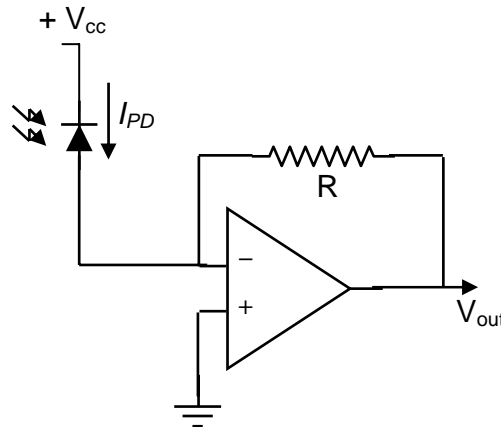
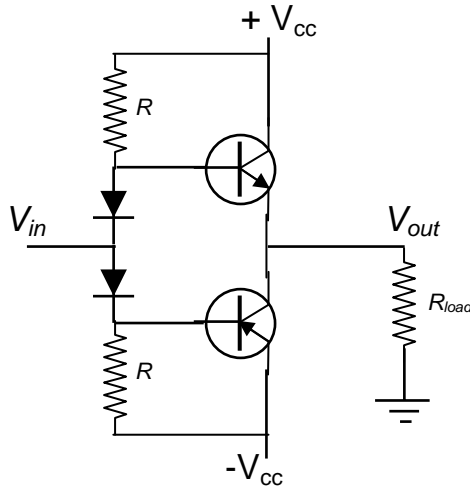


Figure 13: Amplified photodiode in reverse-bias configuration

In practice, the capacitance of the photodiode can send the op-amp into oscillation, so a small feedback capacitor is frequently added in parallel with the feedback resistor  $R$ .

**Design Exercises**

*Design Exercise 10-1:* Analyze the push-pull amplifier shown below and explain the purpose of the diodes. What are reasonable values for R?



*Design Exercise 10-2:* Design an op-amp based high-sensitivity photodiode amplifier for a photodiode with a PN capacitance of 150 pF. The amplifier should have a gain of 1  $\mu\text{A}/\text{V}$ . What is the response speed (i.e. time constant) of the photodiode-amplifier combination?

*Design Exercise 10-3:* Design an op-amp based high-speed photodiode amplifier. Use a reverse-bias configuration with a bias voltage of +15 V. We will assume that the biasing reduces the PN capacitance to 40 pF. The amplifier should have a gain of 1  $\mu\text{A}/\text{V}$ . What is the response speed (i.e. time constant) of the photodiode-amplifier combination?

*Design Exercise 10-4:* Design an op-amp-based 10  $\mu\text{A}$  constant current source in which the load is not grounded. The design may include additional semiconductor components which we have previously used in lab, if you wish.

*Design Exercise 10-5:* The TH10K thermistor is a type of silicon-based resistor which has a resistance of 10 k $\Omega$  at 25  $^{\circ}\text{C}$ , but whose resistance (counter-intuitively) changes by -4.4% per  $^{\circ}\text{C}$ . Design a voltage divider using the TH10K thermistor and a second resistor such that at room temperature the output voltage of the voltage divider is roughly linear with any change in temperature (i.e. the output voltage function has an inflection point at room temperature). You should keep the power dissipated by the thermistor well below 1 mW to avoid self-heating. Design a circuit in which the output voltage changes by about 0.5 V per deg  $^{\circ}\text{C}$  over the range 0  $^{\circ}\text{C}$  – 50  $^{\circ}\text{C}$  and can drive a 5 k $\Omega$  load or larger with minimal effect on the output voltage.